TOSHIBA Photocoupler IRED + Photo-Triac

TLP261J

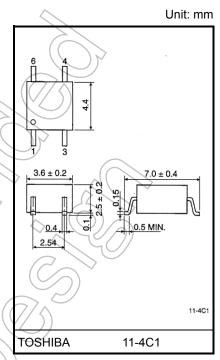
Triac Drivers
Programmable Controllers
AC-Output Modules
Solid-State Relays

The TOSHIBA mini-flat coupler TLP261J is housed in a small-outline package and suitable for surface-mount assembly.

The TLP261J consists of an infrared emitting diode optically coupled to a triac-output photocoupler.

- Peak off-state voltage: 600 V (min)
- Trigger LED current: 10 mA (max)
- On-state current: 70 mA (max)
- Isolation voltage: 3000 Vrms (min)
- Zero-crossing function
- UL-recognized: UL 1577, File No.E67349
- VDE-approved: EN 60747-5-5 (Note 1)

Note 1: When a VDE approved type is needed, please designate the **Option(V4)**.



Weight: 0.09 g (typ.)

 Construction Mechanical Rating Creepage distance: 4.0 mm (min) Clearance: 4.0 mm (min) Insulation thickness: 0.4 mm (min)

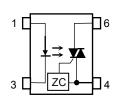
Trigger LED Current

Classification (Note 1)	Trigger LED	Product	
	V _T =3 V, Ta = 25°C		Classification
	Min	Max	Marking
(IFT7)	_	7	Т7
Standard	J) -, (10	T7, blank

Note 1: E.g. (IFT7): TLP261J (IFT7)

Note: Be sure to use standard product type names when submitting type names for safety certification testing, i.e., TLP261J (IFT7): TLP261J.

Pin Configuration



- 1 : Anode
- 3: Cathode
- 4 : Triac Terminal
- 6 : Triac Terminal

Start of commercial production 2003-07



Absolute Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit	
	Forward current	lF	50	mA	
	Forward current derating (Ta ≥ 53°C)	ΔIF / °C	-0.7	mA / °C	
	Peak forward current (100 µs pulse, 100 pps	IFP	1	А	
ED	Reverse voltage		VR	5	V
	Diode power dissipation	P _D	100	mW	
	Diode power dissipation derating (Ta ≥ 53°C	ΔP _D /°C	7-1.4	mW/°C	
	Junction temperature	Tj	125	°C	
	Off-state output terminal voltage	V _{DRM}	600	V	
	0 11 5110	Ta = 25°C		70	m ^
	On-state RMS current	Ta = 70°C	IT(RMS)	40	mA
or	On-state current derating (Ta ≥ 25°C)	ΔITY°C	-0.67	mA / °C	
Detector	Peak on-state current (100 µs pulse, 120 pp	(hp	2	A	
۵	Peak nonrepetitive surge current (P _W = 10 r	TSM	1.2	/))A	
	Output power dissipation	Po	200	// mW	
	Output power dissipation derating (Ta ≥ 25°	ΔPo/°C	-2.0	mW / °C	
	Junction temperature		T _j	(100	°C
Stor	age temperature range	T _{stg}	-55 to 125	°C	
Ope	rating temperature range	Topr	-40 to 100	°C	
Lead	d soldering temperature (10 s)	T _{sol}	260	°C	
Isola	ation voltage (AC, 60 s, R.H ≤ 60 %)	(Note 1)	BVs	3000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Device considered as a two-terminal device: Pins 1 and 3 shorted together and pins 4 and 6 shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply voltage	VAC	_	_	240	V _{ac}
Forward current	lF	15	20	25	mA
Peak on-state current	ITP	_	_	1	Α
Operating temperature	Topr	-25	1	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the devices. Each item also has its own independent guideline document. In developing designs using these products, please confirm the specified characteristics shown in these documents.

Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	I _F = 10 mA	1.0	1.15	1.3	V
ED	Reverse current	I _R	V _R = 5 V	_	_	10	μΑ
	Capacitance	Ст	VF = 0 V, f = 1 MHz	<u>⟨</u> –	30	_	pF
	Peak off-state current	IDRM	V _{DRM} = 600 V		10	1000	nA
	Peak on-state voltage	VTM	I _{TM} = 70 mA	6) 1.7	2.8	V
ctor	Holding current	lн	- (7/2	0.6	_	mA
Detector	Critical rate of rise of off-state voltage	dv / dt	V _{in} = 240 Vrms, Ta = 85 °C (Fig. 1)	200	500	_	V/µs
	Critical rate of rise of commutating voltage	dv / dt(c)	V _{in} = 60 Vrms, I _T = 15 mA (Fig. 1)	<i>></i> –	0.2	_	V/µs

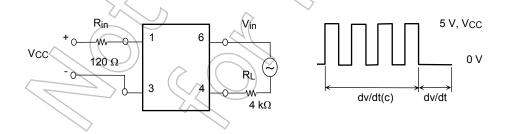
Coupled Electrical Characteristics (Ta = 25°C)

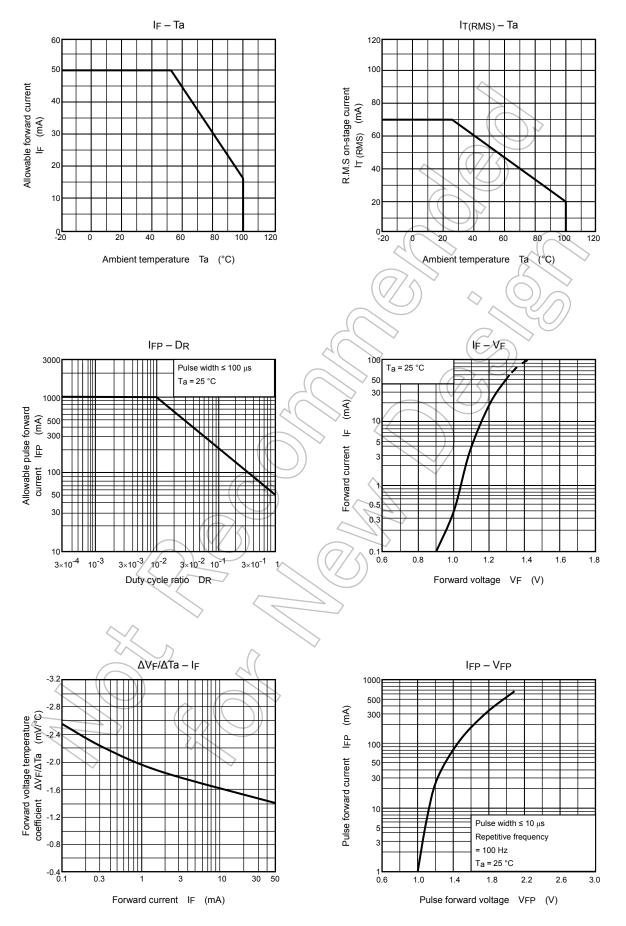
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current	I _{FT}	V _T = 3 V			10	mA
Inhibit voltage	VIH	IF = Rated IFT	(5)	_	20	V
Leakage in inhibited state	l _{IH}	IF = Rated IFT VT = Rated VDRM		200	600	μΑ
Turn-on time	ton	$V_D = 3 \rightarrow 1.5 \text{ V}, \text{ RL} = 20 \Omega$ IF = rated IFT × 1.5	IJ_	30	100	μs

Isolation Characteristics (Ta = 25°C)

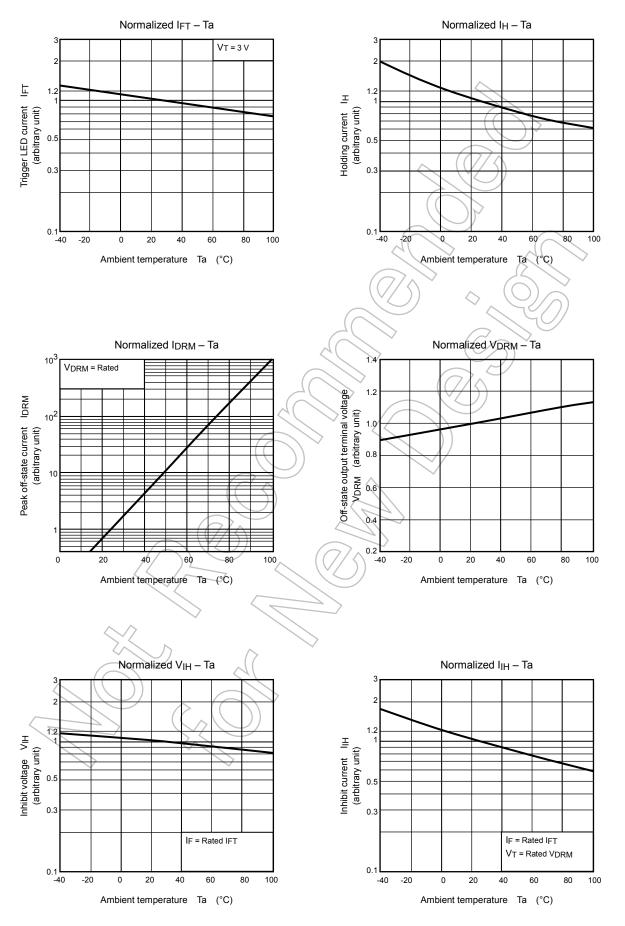
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance (input to output)	Cs	V _S = 0 V, f = 1 MH _z	_	0.8	_	pF
Isolation resistance	Rs	V _S = 500 V, R.H. ≤ 60 %	5×10 ¹⁰	10 ¹⁴	_	Ω
Isolation voltage	BVs	AC, 60 s	3000	_	_	V _{rms}

Fig. 1: dv / dt test circuit





NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



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